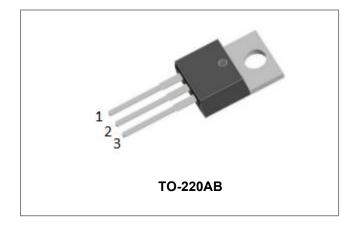


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MBR60100CT SCHOTTKY RECTIFIER



Features

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	Tc=113°C	30(Per Leg) 60(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	280	А

Electrical Characteristics:

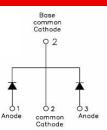
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 30A, Pulse, T _J = 25°C	0.85	0.90	V
	V _{F2}	@ 30A, Pulse, T _J = 125°C	0.76	0.81	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_R$ T _J = 25°C	0.01	1.0	mA
	I _{R2}	$@V_R = rated V_R$ T _J = 125°C	8	20	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25°C, f _{SIG} = 1MHz	400	800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/s

* Pulse width < 300 μ s, duty cycle < 2%

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Circuit Diagram





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Thermal-Mechanical Specifications:

Characteristics	Symbol	Symbol Condition		Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	2.3	°C/W
Typical Thermal Resistance Junction to Case	$R_{\theta CS}$	Mounting surface, smooth and greased	0.24	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	50	°C/W
Typical Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

Ratings and Characteristics Curves

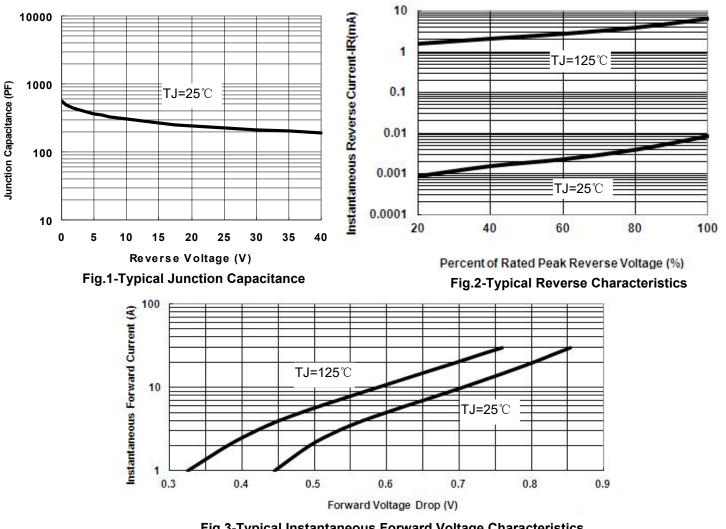


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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RoHS 🗭

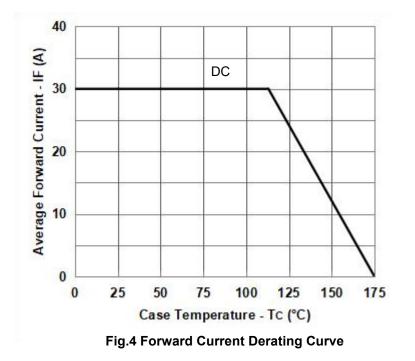


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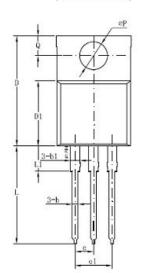
RoHS

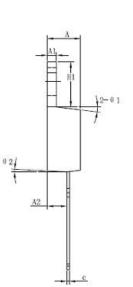
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Mechanical Dimensions TO-220AB







Symbol	Dimensions in millimeters			
	Min	Typical	Max	
A	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	9.65	-	10.67	
е	-	2.54	-	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ΦΡ	-	3.56	-	
Q	2.54	-	3.43	

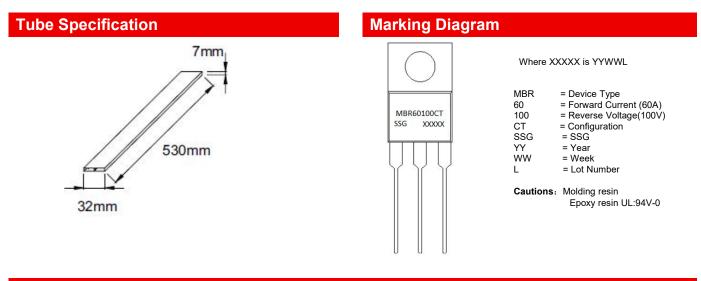
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Ordering Information

Device	Package	Shipping	
MBR60100CT	TO-220AB (Pb-Free)	50 pcs/ tube	

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